



20A05G THRU 20A10G

GENERAL PURPOSE SILICON RECTIFIERS

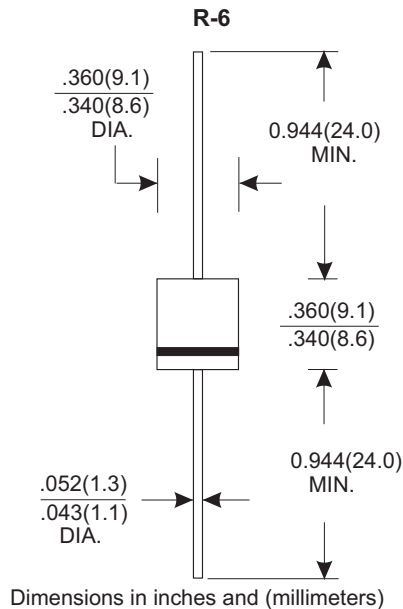
Reverse Voltage - 50 to 1000 Volts Forward Current - 20.0 Ampere

FEATURES

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: Axial leads, solderable per MIL-STD-202, method 208 guaranteed
- * Polarity: Color band denotes cathode end
- * Mounting position: Any
- * Weight: 1.65 grams



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	20A05G	20A1G	20A2G	20A4G	20A6G	20A8G	20A10G	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at Ta=50°C	20.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	700							A
Maximum Instantaneous Forward Voltage at 20.0A	1.0							V
Maximum DC Reverse Current Ta=25°C	10.0							μA
at Rated DC Blocking Voltage Ta=100°C	400							μA
Typical Junction Capacitance (Note 1)	150							pF
Typical Thermal Resistance RθJA (Note 2)	10							°C/W
Operating Temperature Range Tj	-65 — +125							°C
Storage Temperature Range Tstg	-65 — +150							°C

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Thermal Resistance from Junction to Ambient .375" (9.5mm) lead length.

RATING AND CHARACTERISTIC CURVES (20A05G THRU 20A10G)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

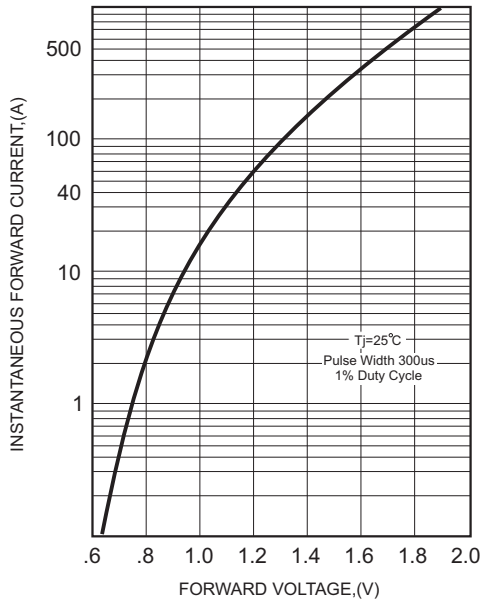


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

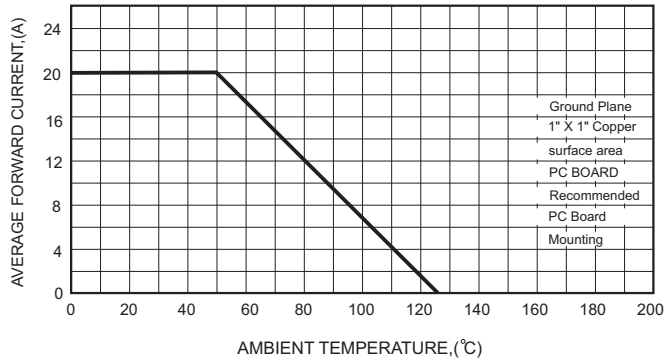


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

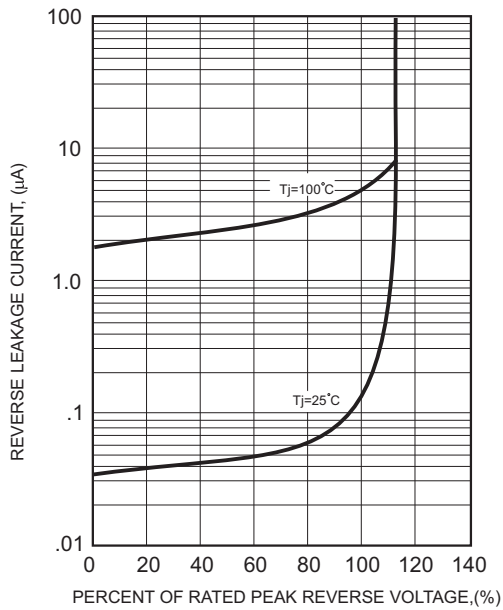


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

